



AMP2112A SOLID STATE HIGH POWER AMPLIFIER

FEATURES

- Class AB linear LDMOS design
- Instantaneous ultra-wide bandwidth
- Rack mounted system
- Designed for broadband EMI/RFI, Lab, BCI applications
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness



ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	1 - 1000 MHz	
Power Output @ Psat	200 Watt Min	150 Watt Min @ 900-1000MHz
Power Output @ P1dB	120 Watt Min / 150 Watt Typ	
Power Gain	53 dB Min	
Power Gain Flatness	4.0 dB p-p Max	Constant input power
Input Return Loss	-10 dB Max	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	43dBm/Tone, Δ = 1MHz
Harmonics 2 nd / 3 rd	-25 dBc / -15 dBc Typ	At rated output power
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	100 - 240 VAC	
Power Consumption	1200 Watt Max	At rated Pout
Input Power Protection	+8 dBm Max	<10 Sec without damage
Load VSWR Protection	∞ : 1	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 133 x 560 mm	R3U - Excluding connectors
Weight	20 kg.	
RF Connectors In / Out	Type-N Female	
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	Or equivalent
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, USB, RS422/485, USB Optional GPIB Interface	Optional Remote Bluetooth applications

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OUTLINE DRAWING

